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DATA SHEET



NPN SILICON RF TRANSISTOR

NE68030 / 2SC4228 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 3-PIN SUPER MINIMOLD

DESCRIPTION

The NE68030 / 2SC4228 is a low supply voltage transistor designed for VHF, UHF low noise amplifier. It is suitable for a high density surface mount assembly since the transistor has been applied 3-pin super minimold package.

FEATURES

- Low noise: NF = 1.9 dB TYP. @ VcE = 3 V, Ic = 5 mA, f = 2 GHz
 - High gain : $|S_{21e}|^2 = 7.5 \text{ dB TYP}$. @ VcE = 3 V, Ic = 5 mA, f = 2 GHz
 - 3-pin super minimold package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE68030-A 2SC4228-A	50 pcs (Non reel)	8 mm wide embossed taping Rin 3 (Collector) face the perferation side of the tape.
NE68030-T1-A 2SC4228-T1-A	3 kpcs/reel	Pin 3 (Collector) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^{\circ}C$)

Parameter	Symbol	Ratings	Unit	
Collector to Base Voltage	Vсво	20	٧	
Collector to Emitter Voltage	VCEO	10	٧	
Emitter to Base Voltage	VEBO	1.5	٧	
Collector Current	lc	35	mA	
Total Power Dissipation	Ptot Note	150	mW	
Junction Temperature	Tj	150	°C	
Storage Temperature	T _{stg}	-65 to +150	°C	

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	VcB = 10 V, IE = 0 mA	-	-	1.0	μΑ	
Emitter Cut-off Current	ІЕВО	V _{EB} = 1 V, I _C = 0 mA	-	-	1.0	μΑ	
DC Current Gain	hfE Note 1	VcE = 3 V, Ic = 5 mA	50	100	250	-	
RF Characteristics							
Gain Bandwidth Product	f⊤	VcE = 3 V, Ic = 5 mA, f = 2 GHz	5.5	8.0	-	GHz	
Insertion Power Gain	S _{21e} ²	VcE = 3 V, Ic = 5 mA, f = 2 GHz	5.5	7.5		dB	
Noise Figure	NF	VcE = 3 V, Ic = 5 mA, f = 2 GHz	-	1.9	3.2	dB	
Reverse Transfer Capacitance	Cre Note 2	VcB = 3 V, IE = 0 mA, f = 1 MHz	-	0.3	0.7	pF	

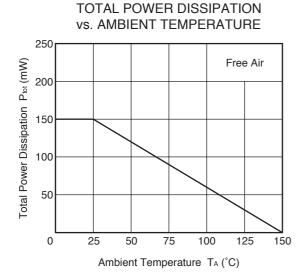
Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

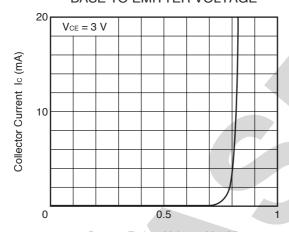
hfe CLASSIFICATION

Rank	R43	R44	R45
Marking	R43	R44	R45
h _{FE} Value	50 to 100	80 to 160	125 to 250

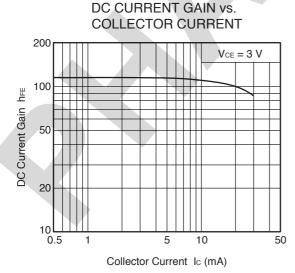
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



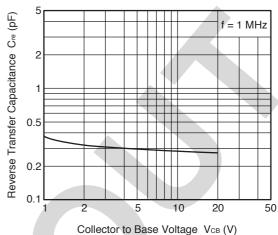
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



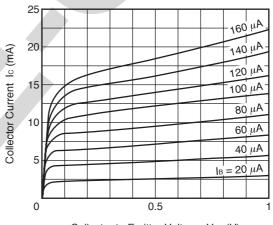
Base to Emitter Voltage $V_{BE}(V)$



REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

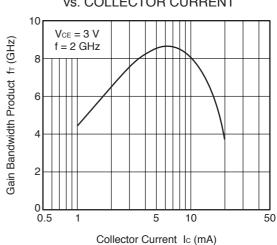


COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE

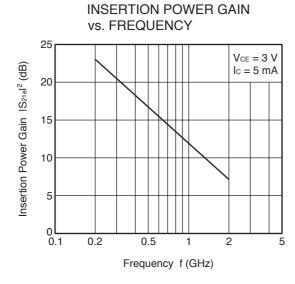


Collector to Emitter Voltage $\ V_{CE}(V)$

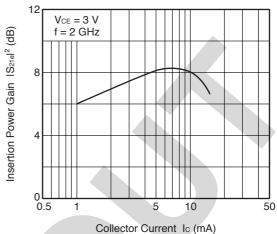
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



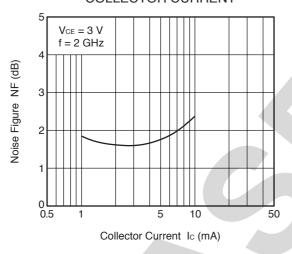
Remark The graphs indicate nominal characteristics.



INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



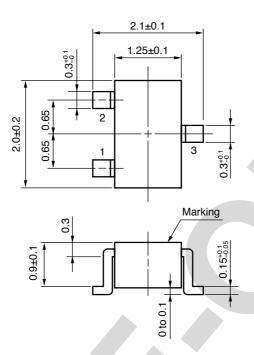
Remark The graphs indicate nominal characteristics.

S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN SUPER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
- 2. Base
- 3. Collector

(EIAJ: SC-70)

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